



PATENT 005586/D8326 (81784.0208)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Hidenori OGATA et al.

Serial No: 09/291,538

Filed: April 14, 1999

Confirmation No. 2245

For: LASER ANNEAL METHOD OF A

SEMICONDUCTOR LAYER

PETITION FOR EXTENSION OF TIME

Mail Stop RCE Commissioner for Patents P. O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

In accordance with 37 C.F.R. 1.136, Applicant respectfully petitions the Commissioner for a three-month extension of time extending to September 10, 2003, the period for response to the final Office Action dated March 10, 2003. A check for \$930 is enclosed. The responsive paper(s) are attached.

Please charge any insufficiency or credit any overpayment to Deposit Account

No. 50-1314. A copy of this petition is enclosed.

09/16/2003 DTESSEN1 00000162 0929153A

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930.00 DP

Date: September 10, 2003

Respectfully submitted,

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Examiner: M.A. Wilczewski

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed

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Commissioner for Patent

P. O. Box 1450, Alexandria, VA 22313-

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September 10, 2003

Date of Deposit

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